

ECH8606

Ultrahigh-Speed Switching Applications

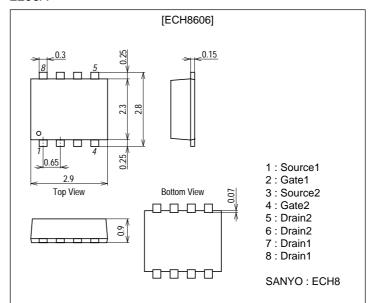
Features

- · Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit : mm

2206A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		6	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	40	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)1unit	1.3	W
Total Dissipation	PT	Mounted on a ceramic board (900mm ² X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	1.0		2.4	V
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Marking : KI

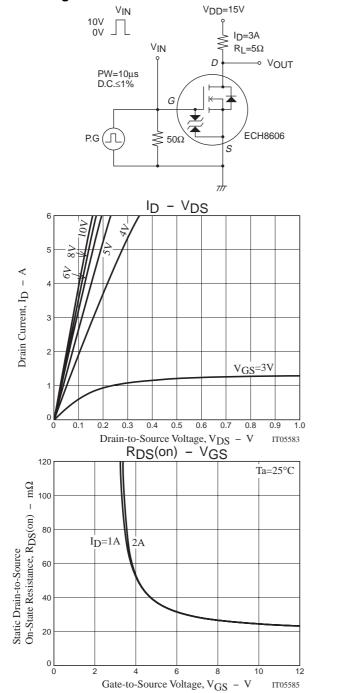
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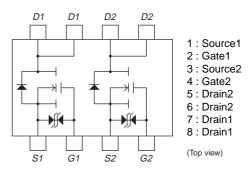
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

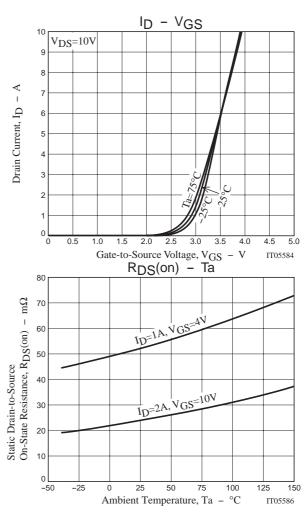
Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	3.3	5		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=2A, VGS=10V		25	34	mΩ
	RDS(on)2	ID=1A, VGS=4V		52	75	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		510		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		105		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		70		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		15		ns
Rise Time	tr	See specified Test Circuit.		74		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		43		ns
Fall Time	tf	See specified Test Circuit.		37		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =6A		11		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =6A		1.9		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =6A		2.9		nC
Diode Forward Voltage	VSD	IS=6A, VGS=0		0.85	1.2	V

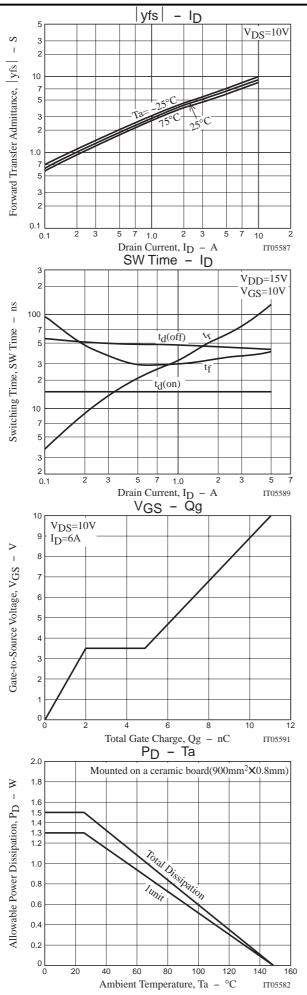
Switching Time Test Circuit

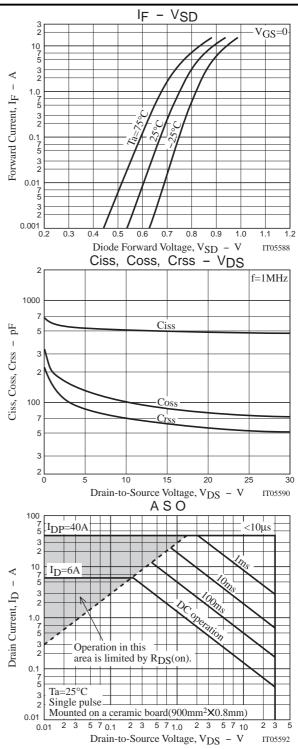


Electrical Connection









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